UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/815,287	04/01/2004	Soon-Il Ahn	8054-57 (LW9035US/KE) 8332	
22150 E CHAIL& AS	7590 05/31/2007 SSOCIATES LLC		EXAMINER	
F. CHAU & ASSOCIATES, LLC 130 WOODBURY ROAD			PERKINS, PAMELA E	
WOODBURY,	NY 11797		ART UNIT PAPER NUMBER	
			2822	
		•	MAIL DATE	DELIVERY MODE
	•		05/31/2007	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

		Application No.	Applicant(s)				
		10/815,287	AHN ET AL.				
	Office Action Summary	Examiner	Art Unit				
		Pamela E. Perkins	2822				
T	he MAILING DATE of this communication appo	ears on the cover sheet with th	e correspondence address				
A SHOR WHICHE - Extension after SIX ( - If NO peri - Failure to Any reply	TENED STATUTORY PERIOD FOR REPLY EVER IS LONGER, FROM THE MAILING DA as of time may be available under the provisions of 37 CFR 1.13 (6) MONTHS from the mailing date of this communication. od for reply is specified above, the maximum statutory period w reply within the set or extended period for reply will, by statute, received by the Office later than three months after the mailing atent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATI 6(a). In no event, however, may a reply be ill apply and will expire SIX (6) MONTHS fr cause the application to become ABANDO	ON.  e timely filed  om the mailing date of this communication.  NED (35 U.S.C. § 133).				
Status							
1)⊠ Re	sponsive to communication(s) filed on 11 Ma	ay 2007.					
2a) ☐ Th	This action is <b>FINAL</b> . 2b)⊠ This action is non-final.						
3)∐ Sir	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is						
clo	sed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11,	453 O.G. 213.				
Disposition	of Claims						
4)⊠ Cla	4)⊠ Claim(s) <u>1-19</u> is/are pending in the application.						
4a)	4a) Of the above claim(s) is/are withdrawn from consideration.						
5)∏ Cla	5) Claim(s) is/are allowed.						
6)⊠ Cla	aim(s) <u>1-19</u> is/are rejected.						
	aim(s) is/are objected to.						
8) Cla	aim(s) are subject to restriction and/or	election requirement.					
Application	Papers	•					
9) <u></u> Th€	e specification is objected to by the Examiner	•					
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner.							
. Ap	plicant may not request that any objection to the o	drawing(s) be held in abeyance.	See 37 CFR 1.85(a).				
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).							
11)∐ The	e oath or declaration is objected to by the Ex	aminer. Note the attached Offi	ce Action or form PTO-152.				
Priority und	er 35 U.S.C. § 119	•					
12) <u></u> Ack a)	knowledgment is made of a claim for foreign All b) ☐ Some * c) ☐ None of:	priority under 35 U.S.C. § 119	(a)-(d) or (f).				
1.[	1. Certified copies of the priority documents have been received.						
2.[	2. Certified copies of the priority documents have been received in Application No						
3.[	Copies of the certified copies of the prior	ity documents have been rece	ived in this National Stage				
	application from the International Bureau	, , , , , , , , , , , , , , , , , , , ,					
* See the attached detailed Office action for a list of the certified copies not received.							
			·				
		•	•				
Attachment(s)							
	References Cited (PTO-892)	4) Interview Summ Paper No(s)/Mai					
3) Information	Draftsperson's Patent Drawing Review (PTO-948) on Disclosure Statement(s) (PTO/SB/08) o(s)/Mail Date	5) Notice of Inform: 6) Other:					

Art Unit: 2822

### **DETAILED ACTION**

This office action is in response to the filing of the request for reconsideration on 11 May 2007. Claims 1-19 are pending.

Applicant's request for reconsideration of the finality of the rejection of the last Office action is persuasive and, therefore, the finality of that action is withdrawn.

# Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claim 1 is rejected under 35 U.S.C. 102(e) as being anticipated by Sandstrom et al. (6,700,600).

Sandstrom et al. disclose a method for exposing a layer with a light where a mask including a pattern shape is disposed over the layer formed on a substrate; and scanning the mask with the light, such that a direction of the scanning is substantially perpendicular to a longitudinal direction of the pattern shape to form a pattern (Fig. 1 & 2; col. 1, lines 26-44; col. 2, lines 13-45; col. 3, lines 10-26; claim 1).

Art Unit: 2822

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 2-4 are rejected under 35 U.S.C. 103(a) as being unpatentable over Sandstrom et al. in view of Isobe et al. (2003/0218169).

Sandstrom et al. disclose the subject matter claimed above, including the use of the mask in the formation of circuit patterns, however Sandstrom et al. does not disclose specifically using the mask in the formation of data lines, pixel electrodes and thin film transistors.

Referring to claim 2, Isobe et al. disclose a method for exposing a layer with a light where a mask including a pattern shape is formed over the layer formed on a substrate; and scanning the mask with the light (para. 29 & 92). Isobe et al. further disclose wherein the pattern formed on the substrate is electrically coupled with a conductive pattern (111) disposed in a different layer from the pattern to generate a coupling capacitance, wherein an insulation layer (110) is disposed between the pattern and the conductive pattern (111) (para 87-90).

Referring to claim 3, Isobe et al. disclose wherein the pattern formed on the substrate corresponds to a data line (para. 90-92).

Referring to claim 4, Isobe et al. disclose forming an insulation layer (615) on the substrate having the data line; and forming a pixel electrode (670) as a conductive

Art Unit: 2822

pattern on the substrate having the insulation layer (615), wherein a direction of scanning is substantially perpendicular to a longitudinal direction of the data line during an exposure process for forming the pixel electrode (670) (para. 29 & 159-163).

Since Sandstrom et al. and Isobe et al. are both from the same field of endeavor, a method for exposing a layer with a light, the purpose disclosed by Isobe et al. would have been recognized in the pertinent art of Sandstrom et al. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify Sandstrom et al. by using the mask in the formation of data lines and pixel electrodes as taught by Isobe et al. to prevent the lowering of the mobility of the thin film transistor (para. 20).

Claims 5, 6 and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Sandstrom et al. in view of Isobe et al. as applied to claim 1 above, and further in view of Kim (2003/0211404).

Sandstrom et al. in view of Isobe et al. disclose the subject matter claimed above except the substrate corresponds to a substrate of a patterned vertical alignment mode liquid crystal display device having a size of nineteen inches and one cell is exposed by the mask.

Kim discloses a method for exposing a layer with a light where a mask including a pattern shape is formed over the layer formed on a substrate; and scanning the mask with the light to form a pattern (para. 17 & 18). Kim further discloses the substrate having a size of more than or equal to seventeen inches, wherein the substrate

Art Unit: 2822

corresponds to a substrate of a patterned vertical alignment mode liquid crystal display device having a size of nineteen inches (para. 10 and 14-16). Kim also discloses exposing one pattern (cell) using the mask (Fig. 4; para. 41).

Since Sandstrom et al. and Kim are both from the same field of endeavor, a method for exposing a layer with a light, the purpose disclosed by Kim would have been recognized in the pertinent art of Sandstrom et al. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify Sandstrom et al. by the substrate corresponds to a substrate of a patterned vertical alignment mode liquid crystal display device having a size of nineteen inches and one cell is exposed by the mask as taught by Kim to increase the surface area of the liquid crystal display.

Claim 7 is rejected under 35 U.S.C. 103(a) as being unpatentable over Sandstrom et al. in view of Isobe et al. as applied to claim 1 above, and further in view of Tanuma et al. (5,718,839).

Sandstrom et al. in view of Isobe et al. disclose the subject matter claimed above except an interval between the data line and a pixel electrode formed on the substrate being at least 6.25  $\mu$ m.

Tanuma et al. disclose a method for exposing a layer with a light where a mask including a pattern shape is formed over the layer formed on a substrate; and scanning the mask with the light to form a pattern (Fig. 20b; col. 26, lines 39-54). Tanuma et al.

Art Unit: 2822

further disclose an interval between the data line and a pixel electrode formed on the substrate is 10  $\mu$ m or less (col. 8, lines 40-56).

Since Sandstrom et al. and Tanuma et al. are both from the same field of endeavor, a method for exposing a layer with a light, the purpose disclosed by Tanuma et al. would have been recognized in the pertinent art of Sandstrom et al. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify Sandstrom et al. by an interval between the data line and a pixel electrode formed on the substrate being 10  $\mu$ m or less as taught by Tanuma et al. to prevent abnormalities in the liquid crystals (col. 8, lines 40-56).

Claims 9, 10, 14, 15 and 19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yang et al. (2003/0213966) in view of Sandstrom et al.

Yang et al. disclose a method for the formation of circuit patterns where a gate wiring layer is formed on a substrate (10); etching the gate wiring layer to form a gate wiring that includes a gate line (22), a gate pad (end) (24) and a gate electrode (26) (para. 235); forming a gate insulation layer (30) on the substrate (10) having the gate wiring formed on the substrate (10) (para. 236); forming a semiconductor layer pattern (40) and an ohmic contact layer pattern (50) on the gate insulation layer (30) in sequence (para. 236 & 237); forming a data wiring layer on the substrate (10) having the semiconductor layer pattern (40) and the ohmic contact layer pattern (50); forming a photoresist layer on the data wiring layer; disposing a mask including a pattern shape over the photoresist layer formed on the substrate (10); the mask with a light, such that

Art Unit: 2822

a direction of the scanning is patterning the data wiring layer to form a data wiring including a data line (62) crossing the gate line (22), a data pad (end) (68) connected to the data line (62), a source electrode (65) connected to the data line (62), and a drain electrode (66) in an opposite position to the source electrode (65) around the gate electrode(26) (para. 237 & 238); forming a protection layer (70) on the substrate (10) having the source and drain electrodes (65 &66) formed thereon; patterning the gate insulation layer (30) and the protection layer (70) to form contact holes (72, 74, 76, 78), the contact holes exposing the gate pad (end) (24), the data pad (end) (68) and the drain electrode (66), respectively (para. 239); forming a transparent conductive layer; and etching the transparent conductive layer to form an supplementary gate pad (auxiliary gate end) (84) being electrically connected to the gate pad (end) (24), a(n) supplementary data pad (auxiliary data end) (88) being electrically connected to the data pad (end) (68), and a pixel electrode (84) being electrically connected to the drain electrode (66) (para. 239 & 240). Yang et al. further disclose the photosensitive layer pattern including a first portion, a second portion thicker than the first portion, and a third portion thinner than the first portion (para. 140; claim 75). Yang et al. also disclose wherein the first portion is positioned between the source electrode and the drain electrode, and the second portion is positioned over an upper portion of the data wiring (para. 140).

Yang et al. do not disclose scanning substantially perpendicular to a longitudinal direction of the pattern shape to expose the photoresist layer.

Art Unit: 2822

Sandstrom et al. disclose a method for exposing a layer with a light where a mask including a pattern shape is disposed over the layer formed on a substrate; and scanning the mask with the light, such that a direction of the scanning is substantially perpendicular to a longitudinal direction of the pattern shape to form a pattern (Fig. 1 & 2; col. 1, lines 26-44; col. 2, lines 13-45; col. 3, lines 10-26; claim 1).

Since Yang et al. and Sandstrom et al. are both from the same field of endeavor, a method for the formation of circuit patterns, the purpose disclosed by Sandstrom et al. would have been recognized in the pertinent art of Yang et al. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify Yang et al. by canning substantially perpendicular to a longitudinal direction of the pattern shape to expose the photoresist layer as taught by Sandstrom et al.

Claims 11 and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yang et al. in view of Sandstrom et al. as applied to claims 9 and 14 above, and further in view of Tanuma et al.

Yang et al. in view of Sandstrom et al. disclose the subject matter claimed above except an interval between the data line and a pixel electrode formed on the substrate being at least  $6.25 \, \mu \text{m}$ .

Tanuma et al. disclose a method for exposing a layer with a light where a mask including a pattern shape is formed over the layer formed on a substrate; and scanning the mask with the light to form a pattern (Fig. 20b; col. 26, lines 39-54). Tanuma et al.

Art Unit: 2822

further disclose an interval between the data line and a pixel electrode formed on the substrate is 10  $\mu$ m or less (col. 8, lines 40-56).

Since Yang et al. and Tanuma et al. are both from the same field of endeavor, a method for exposing a layer with a light, the purpose disclosed by Tanuma et al. would have been recognized in the pertinent art of Yang et al. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify Yang et al. by an interval between the data line and a pixel electrode formed on the substrate being 10  $\mu$ m or less as taught by Tanuma et al. to prevent abnormalities in the liquid crystals (col. 8, lines 40-56).

Claims 12, 13, 17 and 18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yang et al. in view of Sandstrom et al. as applied to claims 9 and 14 above, and further in view of Kim.

Yang et al. in view of Sandstrom et al. disclose the subject matter claimed above except the substrate corresponds to a substrate of a patterned vertical alignment mode liquid crystal display device having a size of nineteen inches and one cell is exposed by the mask.

Kim discloses a method for exposing a layer with a light where a mask including a pattern shape is formed over the layer formed on a substrate; and scanning the mask with the light to form a pattern (para. 17 & 18). Kim further discloses the substrate having a size of more than or equal to seventeen inches, wherein the substrate corresponds to a substrate of a patterned vertical alignment mode liquid crystal display

Art Unit: 2822

device having a size of nineteen inches (para. 10 and 14-16). Kim also discloses exposing one pattern (cell) using the mask (Fig. 4; para. 41).

Since Yang et al. and Kim are both from the same field of endeavor, a method for exposing a layer with a light, the purpose disclosed by Kim would have been recognized in the pertinent art of Yang et al. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify Yang et al. by the substrate corresponds to a substrate of a patterned vertical alignment mode liquid crystal display device having a size of nineteen inches and one cell is exposed by the mask as taught by Kim to increase the surface area of the liquid crystal display.

Referring to claim 18, Kim discloses simultaneously exposing a plurality of cells using the mask (Fig. 5A; para. 44).

### Response to Arguments

Applicant's arguments, see the request of reconsideration, filed 27 July 2006, with respect to the rejection(s) of claim(s) 1-19 under 35 U.S.C. 102 and 103 have been fully considered and are persuasive. Therefore, the rejection has been withdrawn. However, upon further consideration, a new ground(s) of rejection is made in view of Sandstrom et al. (6,700,600).

### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Pamela E. Perkins whose telephone number is (571)

Application/Control Number: 10/815,287 Page 11

Art Unit: 2822

272-1840. The examiner can normally be reached on Monday thru Friday, 8:30am to 5:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Zandra Smith can be reached on (571) 272-2429. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

PEP 25 May 2007.

Zandra V. Smith
Supervisory Patent Examiner